Name :	
Roll No. :	A Date (V Consider Ind Conference)
Invigilator's Signature :	

CS/M.Tech (ECE)/SEM-2/PGEC-203/2013 2013 OPTOELECTRONICS & DISPLAY DEVICES

Time Allotted : 3 Hours

Full Marks : 70

The figures in the margin indicate full marks. Candidates are required to give their answers in their own words as far as practicable.

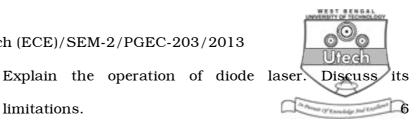
Answer Question No. ${f 5}$ and any *three* from the rest.

1.	a)	Describe double heterostructure surface emitter LED.			
	b)	Make a relative comparison of output of surface an			nd
		edge	e emitter LEDs.		4
	c)	Exp	lain the function of resonance cavity in L	ASER.	3
	d)	Wha	at is <i>Q</i> -switching in Ruby Laser ?		4
	e) Compare different types of Lasers.			4	
2.	a)	Describe the following :		9	
		i)	Population in version		
		ii)	Coherent sources		
		iii)	Stimulating emission.		
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limitations.

b)



c) What is heterostructure laser ? How are they better compared to diode laser ? 5

3. Explain the spectral response of human eye and its a) relation with energy band of semiconductors. 5

- b) Describe the following : 3×5
 - Solar cell construction i)
 - ii) Phototransistor
 - iii) Optocoupler.
- 4. Briefly discuss the limiting factors for LED emission and a) its remedy. 6
 - Explain in detail Edge emitting LED. 4 b)
 - Give the typical modulation circuit for a LED. c) 3
 - d) Give the explanation of the performance of LED in terms 3 of temperature.
 - Discuss a common photo-conductive cell based of CdS e) and its limitation and spectral response. 4

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b) **Coherent sources**

5.

a)

- Optical emission in semiconductors c)
- PIN photodetectors. d)

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